Conductivity and Dielectric Studies on Combustion Derived Self-Doped Ceria Nanoparticles

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ABSTRACT

A series of Ce(0–25 mol%) doped ceria nanoparticles were prepared by low temperature combustion process using the fuel oxalylidyldihydrizide (ODH). Crystallographic information, formation of phase and micro structural details of prepared samples was obtained using powder X-ray diffraction (PXRD) technique, Fourier transmission infrared (FTIR) spectroscopy and field emission scanning electron microscope (FESEM) technique respectively. The size (10–30 nm) of self-doped ceria nanoparticles are evaluated by transmission electron microscope (TEM). PXRD studies confirm the fluorite structure of nanoceria with JCPDS card No. 034-0394. Conductivity and dielectric studies for self-doped ceria nanoparticle were performed in the applied frequency from 20 Hz to 10 MHz and at different temperatures (200–560 °C). The temperature and frequency dependence of the conductivity and dielectric properties of prepared samples showed major effect of the dopant concentration. Dielectric constant and tangent loss of prepared samples decreased sharply with increasing frequency.

1. Introduction

Rare earth oxides are being used as polishing compounds, phosphors, catalysts, etc., due to their good optical, electrical and chemical properties [1]. Cerium oxide has attracted the interest of many researchers due to its diverse applications in different areas like biomedical sciences, materials sciences etc., [2-6]. Compared to undoped nanoceria, rare earth doped nanoceria was found to be true electrolyte material for the application of solid oxide fuel cells in medium temperature 500–700 °C contrast to conventional yttria-stabilized zirconia [7]. The impurities like aliovalent-dopants [8-12] addition drastically increase the ionic conductivity of undoped ceria due to the creation of oxygen vacancies that indirectly help the migration of ions. In doped ceria, oxygen ion conductivity takes place on basis of hopping mechanism [13] and has a direct bearing on the type and ratio of dopant ion concentration of and also on the oxygen vacancies and defect structure. The major problem in solid electrolyte materials is the increase of conductivity due to electrons, high operating temperature reduces the valence state of Ce3+ to Ce4+ [14] and segregation/splitting-up of impurities at grain boundaries [15,16] leading to poor long-term stability. The correlation between dielectric behaviour and ionic conductivity for perovskite dielectric systems such as multiferroics, ferroelectrics and antiferroelectrics has been well studied [17-19]. In the present work, structural, morphology and AC conductivity and dielectric studies were investigated for CeN0.5Ce25 mol% doped ceria nanopowder. Low temperature densification of nanoceria materials has been achieved by employing wet chemical synthesis methods [21,22]. Among the various wet chemical preparation methods, solution combustion synthesis (SCS) technique is considered to be a relatively better technique due to low cost, fast reaction time (within 5 minutes) and simple experimental setup [23-25]. In the present study, SCS technique has been employed to synthesize the samples.

2. Experimental Methods

2.1 Synthesis

Combustion method is applied to synthesise CeO2:Ce4+ (0–25 mol%) nanopowder using laboratory prepared oxalylidyldihydrizide (ODH) as fuel. Stoichiometric quantities of cerium nitrate (Ce(NO3)2·6H2O) and ODH (C4H12N2O) were added into a beaker containing 35 mL of double distilled water and then the solution was blended for about 5 min to obtain a homogeneous solution. The solution containing beaker was kept in a preheated high temperature furnace maintained at 400 ± 10 °C to initiate the combustion process and to obtain the nano powder sample.

2.2 Characterization

PXRD patterns of all the sample are obtained using Powder X-ray diffract-meter [Bruker AXS D8 and Cu Kα = 1.5415 Å] in 20°-80° diffraction angle (2θ) range. The Fourier transform infrared (FTIR) spectra of prepared samples were examined at room temperature using IR Affinity-1 (Shimadzu, Japan) spectrometer. The micro-structural information of the samples was obtained by examining them using FESEM instrument (Tescan-Mira 3 LMH, magnification: 2X to 10,000,000X, accelerating voltage: 50 V to 30 kV in steps of 10 V). High resolution transmission electron microscope (HR-TEM) images of the nanopowder were analysed [Jeol /JEM-2100, accelerating voltage up to 200 kV] to determine particle size. Debye - Scherrer formula was used to determine crystallite size of nanopowder. The calcined samples were subjected to a uniaxial pressure of 6.5 tons/m² to obtain pellets. Mechanical Strength of the pellets is increased by sintering them at 600 °C for 2 hours. The above and below surfaces of the circular pellets were uniformly coated with conducting material like silver paste. The AC conductivity and dielectric behaviour of the samples were studied at different temperatures (200–560 °C) and at different frequencies (20 Hz – 10 MHz) using precision impedance analyzer (Model 6515B-15MHz series, Wayne Kerr electronics).

3. Result and Discussion

Fig. 1 represents the PXRD patterns of undoped and CeO2:Ce4+ (0–25 mol%) nanoparticles, the sharp intense peaks related to the miller indices (111), (2 0 0), (2 2 0), (3 1 1), (2 2 2), (4 0 0) and (3 3 1) confirming the cubic fluorite structure of the samples [JCPDS card No. 034-0394]. Debye
Scherrer’s formula was employed to determine crystallite size ‘D’ (10-20 nm) [26] of the samples,

\[ D = \frac{K \lambda}{\beta \cos \theta} \]  

(1)

where, K, \( \lambda \), X, and \( \beta \) represents shape factor (spherical structure), wavelength of rays and band width of diffraction peak.

**Fig. 1** PXRD patterns of (a) undoped CeO\(_2\), (b) CeO\(_2\)Ce\(^{4+}\) (5 mol%), (c) CeO\(_2\)Ce\(^{4+}\) (10 mol%), (d) CeO\(_2\)Ce\(^{4+}\) (15 mol%), (e) CeO\(_2\)Ce\(^{4+}\) (20 mol%), (f) CeO\(_2\)Ce\(^{4+}\) (25 mol%)

**Fig. 2** SEM pictures of CeO\(_2\)Ce\(^{4+}\) (15 mol%)

**Fig. 3** (a) TEM and (b) HRTEM images of CeO\(_2\)Ce\(^{4+}\) (15 mol%) nanoparticles

**Fig. 4** FTIR graphs of (a) undoped CeO\(_2\), (b) CeO\(_2\)Ce\(^{4+}\) (5 mol%), (c) CeO\(_2\)Ce\(^{4+}\) (10 mol%), (d) CeO\(_2\)Ce\(^{4+}\) (15 mol%), (e) CeO\(_2\)Ce\(^{4+}\) (20 mol%), (f) CeO\(_2\)Ce\(^{4+}\) (25 mol%)

**Fig. 5** The variation of relative dielectric constant with the applied frequency in the temperature range 200 °C-560 °C of 15 mol% Ce\(^{4+}\) doped CeO\(_2\) nanoparticles

FESEM images of pure and Ce\(^{4+}\) doped ceria nanoparticles depicted in Fig. 2 indicate the presence of large number of voids and agglomerates. This implies a spongy and porous morphology of both the samples, thereby indicating insignificant influence of dopant ions on morphology. During the combustion process large quantities of gases get expelled leading to the formation of voids and porous structures [27, 28]. TEM and HR-TEM images of CeO\(_2\)Ce\(^{4+}\) (15 mol%) samples were showed in Fig. 3. Fig. 3a indicates agglomerated non-uniform sized and nearly spherical structures with average particle size in the 10-30 nm range. Polycrystalline nature of the samples was observed in the high resolution TEM image (Fig. 3b).

The FTIR spectra of undoped and CeO\(_2\)Ce\(^{4+}\) (0 - 25 mol%) doped ceria shown in Fig. 4 exhibit characteristic absorption at 3430 cm\(^{-1}\), 2921 cm\(^{-1}\), 2847 cm\(^{-1}\), 1630 cm\(^{-1}\), 1338 cm\(^{-1}\), and 1058 cm\(^{-1}\). The absorption at various wave-numbers corresponds to the stretching vibration of the hydrogen bonded OH group (3430 cm\(^{-1}\)), CH\(_2\) group (2921 and 2847 cm\(^{-1}\)) and COO\(^{-}\) group (1630 cm\(^{-1}\)) respectively. Absorption at 1338 cm\(^{-1}\) and 1058 cm\(^{-1}\) correspond to the presence of O–N group [29] and nitrate ions [30] respectively. Finally, the absorptions at 854–404 cm\(^{-1}\) can be ascribed to the characteristic Ce–O vibrations. The absence of adsorbed water and enhancement in the crystallinity of the sample can be ascribed to the decrease in the band intensity due to sintering [31].

The complex dielectric constant of a material consists of an imaginary (\( \varepsilon'' \)) and a real part (\( \varepsilon' \)).

\[ \varepsilon = \varepsilon' + j \varepsilon'' \]  

(2)

\[ \varepsilon'' = \varepsilon' \tan \delta \]  

(3)

\[ \varepsilon' = \frac{\varepsilon''}{\tan \delta} \]  

(4)

where C, A, \( \varepsilon \), and \( \tan \delta \) represent capacitance, thickness, area of the sample, permittivity of free space, and dielectric loss respectively. Fig. 5 represents the frequency- dielectric constant plot of CeO\(_2\)Ce\(^{4+}\) (15 mol%) studied at various temperatures (200-560 °C). It can be inferred from the plot that the real part of dielectric permittivity (\( \varepsilon' \)) shows a sharp upturn at the lower frequency regime and decreases exponentially with rise in applied frequency and relatively constant at higher frequencies regime.

The exponential decay of real part (\( \varepsilon' \)) can be ascribed to reduction of interfacial polarization effect. At low frequency regime the high value of \( \varepsilon' \) is attributed to the existence of polarization of charge carriers (oxygen ions) near the grain boundaries and the consequent creation of a potential barrier. The observed variation of \( \varepsilon' \) with frequency is in agreement with Maxwell-Wagner and Koop’s theory [32, 33]. The increase of real part (\( \varepsilon' \)) with rise in temperature can be ascribed to the swift orientation of electric dipoles [34, 35].

Fig. 6 represents the frequency-dielectric constant plots of all the samples at a particular temperature. It can be observed from the Fig. 6 that \( \varepsilon' \) rises with increase in dopant concentration and becomes maximum for a particular dopant concentration (15 mol%) and thereafter it decreases. This can be ascribed to reduction of defects concentration at higher dopant concentration. Fig. 7 shows that tangent loss (\( \tan \delta \)) versus frequency graph of 15 mol% Ce\(^{4+}\) doped ceria nanoparticles at various temperatures (200-560 °C). The variation between tan \( \delta \) and frequency graph shows same trend exhibited by \( \varepsilon' \). This behaviour is mainly due to the interfacial polarization of dipoles at the interface between the electrode and electrolyte. The presence of relaxation peak at higher temperatures and at a particular frequency can be ascribed to the dipole moment of defect pairs. The decrease of tan \( \delta \) at higher frequencies may be ascribed to the phase lag between the orientation of the dipoles with the applied frequency [36, 37].
frequency and s represent frequency exponent where \(0 < s < 1\) [38]. Hence, the AC conductivity at different temperatures (200–560 °C) in all the synthesized samples follows the universal power law [39].

Fig. 9 shows the graph plotted between conductivity and applied frequency at different self-dopant concentrations for a particular temperature. The observed conductivity behaviour of the all prepared samples can be described with the help of Jump Relaxation Model [40]. It can be observed from the figures that the conductivity is maximum for 15 mol percent self-doped ceria. This can be understood in the light of the inverse relation between the dielectric constant and the columbic force between oxygen vacancy and dopant ion,

\[
F = \frac{-2e^2}{4\pi\varepsilon_0\varepsilon_r r^2}
\]

where r is inter-ionic separation and \(\varepsilon_r\) is dielectric constant of material. It is pertinent to recall here that the variation of dielectric constant and AC conductivity with dopant concentration and temperature is identical. Hence, higher the dielectric constant lower is the columbic interaction and higher is the AC conductivity of the material. The fall in conductivity was observed for 20 mol and 25 mol percent dopant concentration samples can be attributed to lower defects concentration. At higher dopant concentrations, Ce\(^{4+}\) ions compensate for the produced defects because similar ionic radius of dopant ion with host ion.

### 4. Conclusion

Ce\(^{4+}\) doped ceria nanopowder was synthesized using solution combustion route. PXRD studies reveal cubic fluorite structure of the material. Large voids and porous nature of the samples is confirmed by electron microscopy studies. Temperature, dopant concentration dependence of dielectric constant and conductivity on frequency of Ce\(^{4+}\) doped CeO\(_2\) nanoparticles can be explained on the basis of hopping mechanism of the ions. The relatively higher conductivity observed for 15 mol % self-doped ceria sample can be understood in the light of the inverse relationship between the dielectric constant and columbic interaction force that binds the oxygen vacancy to the dopant ion.

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ia coprecipitation route, \[23\]


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